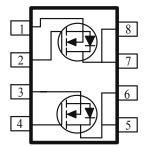
N-Channel 60-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

PRODUCT SUMMARY					
$V_{DS}(V)$	$r_{DS(on)} m(\Omega)$ $I_D(A)$				
60	$35 @ V_{GS} = 10V$	±6.4			
	$45 @ V_{GS} = 4.5V$	±5.6			

- Low r_{DS(on)} provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe SOIC-8 saves board space
- Fast switching speed
- High performance trench technology





ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)						
Parameter		Symbol	Limit	Units		
Drain-Source Voltage			60	V		
Gate-Source Voltage			±20	V		
Continuous Drain Current ^a	$T_A=25^{\circ}C$		±6.4			
Continuous Drain Current	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	ъ	±5.2	A		
Pulsed Drain Current ^b			±40			
Continuous Source Current (Diode Conduction) ^a			2	Α		
D	$T_A=25^{\circ}C$	D_	2.1	W		
Power Dissipation ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	1 D	1.3			
Operating Junction and Storage Temperature Range	· · · · · ·	T _J , T _{stg}	-55 to 150	°C		

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Maximum	Units			
M · I · · · · a	t <= 10 sec	D	62.5	°C/W		
Maximum Junction-to-Ambient ^a	Steady State	$R_{\theta JA}$	110	°C/W		

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

SPECIFICATIONS (T _A = 25°C UNLESS OTHERWISE NOTED)							
Davidana Asar	Cb a l	T. (C. 19)	Limits			TT .*4	
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static					•		
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \text{ uA}$	1				
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = 20 \text{ V}$			±100	nA	
Zero Gate Voltage Drain Current	Ipss	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$	1		1	A	
Zero Gate Voltage Diam Current	IDSS	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			10	uA	
On-State Drain Current ^A	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	20			A	
D : G . D : A	_	$V_{GS} = 10 \text{ V}, I_D = 6.4 \text{ A}$	35		35		
Drain-Source On-Resistance ^A	fDS(on)	$V_{GS} = 4.5 \text{ V}, I_D = 5.6 \text{ A}$			45	mΩ	
Forward Tranconductance ^A	gs	$V_{DS} = 15 \text{ V}, I_D = 6.4 \text{ A}$		11		S	
Diode Forward Voltage	V_{SD}	$I_S = 2.0 \text{ A}, V_{GS} = 0 \text{ V}$			1.2	V	
Dynamic ^b							
Total Gate Charge	Qg	Vac = 20 V Vac = 4.5 V		12.5			
Gate-Source Charge	Qgs	$V_{DS} = 30 \text{ V}, V_{GS} = 4.5 \text{ V},$ $I_{D} = 6.4 \text{ A}$		2.4		nC	
Gate-Drain Charge	Qgd	ID = 6.4 A		2.6		<u> </u>	
Switching					•		
Turn-On Delay Time	t _{d(on)}			11			
Rise Time	$t_{\rm r}$	$V_{\rm DD} = 30 \ V, \ R_L = 30 \ \Omega \ , \ {\rm Id} = 1 \ A,$ $V_{\rm GEN} = 10 \ V$		8		nS	
Turn-Off Delay Time	td(off)			19			
Fall-Time	t_{f}			6			

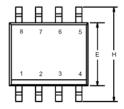
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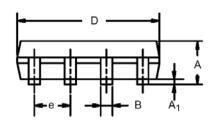
- a. Pulse test: $PW \le 300us duty cycle \le 2\%$.
- b. Guaranteed by design, not subject to production testing.

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Package Information

SO-8: 8LEAD





	MILLIMETERS		INC	HES	
Dim	Min	Max	Min	Max	
Α	1.35	1.75	0.053	0.069	
A ₁	0.10	0.20	0.004	0.008	
В	0.35	0.51	0.014	0.020	
С	0.19	0.25	0.0075	0.010	
D	4.80	5.00	0.189	0.196	
E	3.80	4.00	0.150	0.157	
е	1.27 BSC		0.050 BSC		
Н	5.80	6.20	0.228	0.244	
h	0.25	0.50	0.010	0.020	
L	0.50	0.93	0.020	0.037	
q	0°	8°	0°	8°	

